



STP11N65M2 Information



For Reference Only

Part Number STP11N65M2

Manufacturer STMicroelectronics

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 650V 7A TO-220AB

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









STP11N65M2 Specifications

Manufacturer Part Number	STP11N65M2
Manufacturer	STMicroelectronics
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	MDmesh? II Plus
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	7A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	12.5nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	410pF @ 100V
Vgs (Max)	±25V
FET Feature	-
Power Dissipation (Max)	85W (Tc)
Rds On (Max) @ Id, Vgs	670 mOhm @ 3.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220
Package / Case	TO-220-3
	Report errors?

STP11N65M2 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

STP11N65M2 Payment Methods



















STP11N65M2 Shipping Methods













If you have any question about STP11N65M2, please do not hesitate to contact us!

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